

#### **400V PNP HIGH VOLTAGE TRANSISTOR IN SOT23**

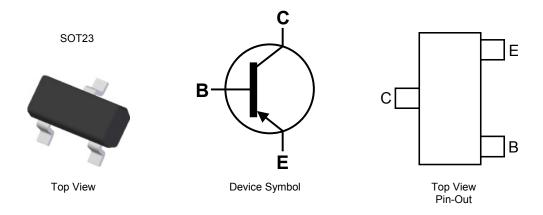
#### **Features**

- BV<sub>CEO</sub> > -400V
- I<sub>C</sub> = -150mA high Continuous Collector Current
- I<sub>CM</sub> = -500mA Peak Pulse Current
- 500mW Power Dissipation
- Excellent h<sub>FE</sub> Characteristics Up To -100mA
- Complementary NPN Type: FMMT458
- Totally Lead-Free & Fully RoHS compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
   The FMMT558Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <sup>®</sup>
- Weight: 0.008 grams (Approximate)



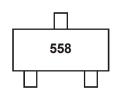
### Ordering Information (Notes 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT558TA	AEC-Q101	558	7	8	3000
FMMT558QTA	Automotive	558	7	8	3000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

### **Marking Information**



558 = Product type Marking Code



## **Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-400	V
Collector-Emitter Voltage	$V_{CEO}$	-400	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I <sub>CM</sub>	-500	mA
Base Current	Ι <sub>Β</sub>	-200	mA

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Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_{D}$	500	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	250	°C/W
Thermal Resistance, Junction to Lead (Note 6)	$R_{ heta JL}$	197	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

## ESD Ratings (Note 7)

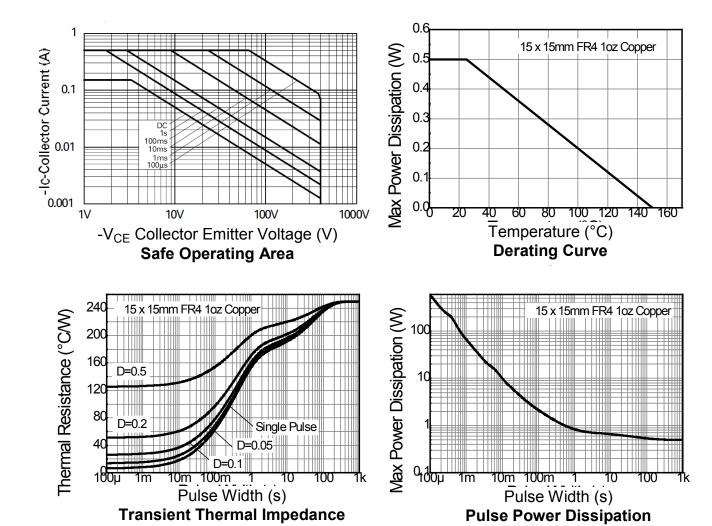
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

Notes:

- 5. For a device surface mounted on 15mm X 15mm X 1.6mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions 6. Thermal resistance from junction to solder-point (at the end of the collector lead).
  7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



## **Thermal Characteristics and Derating information**





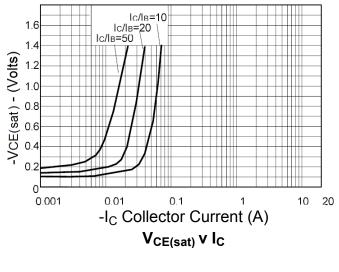
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

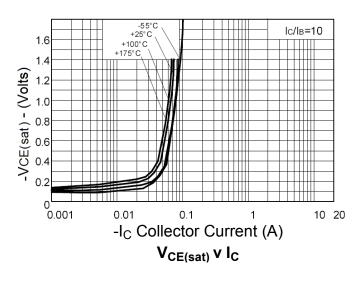
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	-400	-	-	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 8)	BV <sub>CEO</sub>	-400	-	-	V	$I_C = -1mA$
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-7	-	-	V	I <sub>E</sub> = -100μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	-100	nA	V <sub>CB</sub> = -320V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	-100	nA	V <sub>EB</sub> = -5.6V
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	-100	nA	V <sub>CE</sub> = -320V
Static Forward Current Transfer Ratio (Note 8)	h <sub>FE</sub>	100 100 15	- - -	- 300 -	-	$I_C$ = -1mA, $V_{CE}$ = -10V $I_C$ = -50mA, $V_{CE}$ = -10V $I_C$ = -100mA, $V_{CE}$ = -10V
Collector-Emitter Saturation Voltage (Note 8)	V <sub>CE(sat)</sub>	-	-	-200 -500	mV mV	$I_C = -20mA$ , $I_B = -2mA$ $I_C = -50mA$ , $I_B = -6mA$
Base-Emitter Turn-On Voltage (Note 8)	V <sub>BE(on)</sub>	-	-	-0.9	V	I <sub>C</sub> = -50mA, V <sub>CE</sub> = -10V
Base-Emitter Saturation Voltage (Note 8)	V <sub>BE(sat)</sub>	-	-	-0.9	V	$I_C = -50 \text{mA}, I_B = -5 \text{mA}$
Output Capacitance	C <sub>obo</sub>	-	-	5	pF	V <sub>CB</sub> = -20V, f = 1MHz
Transition Frequency	f <sub>T</sub>	50	-	-	MHz	V <sub>CE</sub> = -20V, I <sub>C</sub> = -10mA, f = 20MHz
Turn-On Time	t <sub>on</sub>	-	95	-	ns	V <sub>CE</sub> = -100V, I <sub>C</sub> = -50mA
Turn-Off Time	t <sub>off</sub>	-	1600	-	ns	$I_{B1} = 5mA$ , $I_{B2} = -10mA$

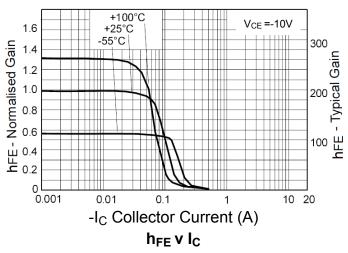
Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%

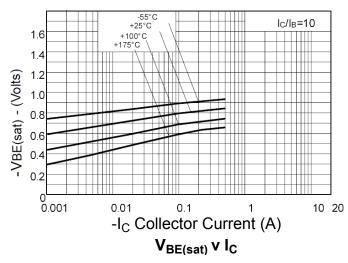


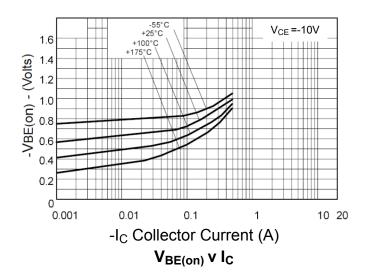
### Typical Electrical Characteristics (@TA = +25°C, unless otherwise specified.)









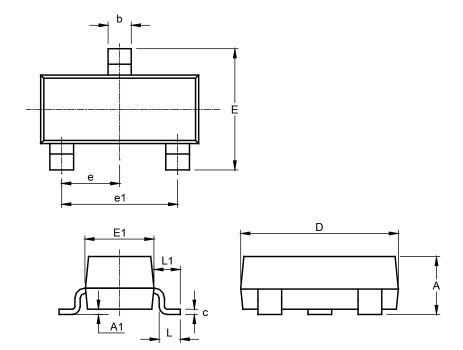




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)

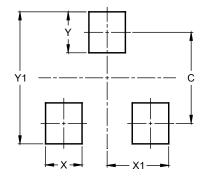


ij	SOT23 Type DN				
Dim	Min	Max	Тур		
Α	0.89	1.12	1.00		
A1	0.01	0.10	0.05		
b	0.30	0.51	0.45		
С	0.08	0.20	0.10		
D	2.80	3.04	3.00		
Е	2.10	2.64	2.42		
E1	1.20	1.40	1.37		
е	0.95 REF				
e1	1.90 REF				
L	0.25	0.60	0.30		
L1	0.45	0.62	0.54		
All Dimensions in mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23 (Type DN)



Dimensions	Value (in mm)		
С	2.0		
X	0.8		
X1	1.35		
Y	0.9		
Y1	29		



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